



#### 25V PNP LOW SATURATION TRANSISTOR IN SOT23

#### Features

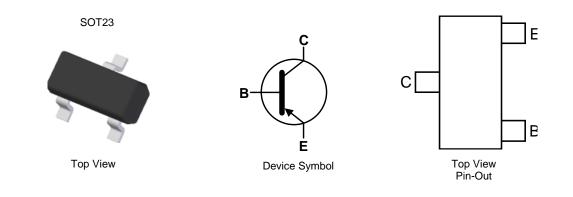
- BV<sub>CEO</sub> > -25V
- BV<sub>CEO</sub> > -35V forward blocking voltage
- I<sub>C</sub> = -3A Continuous Collector Current
- Low Saturation Voltage, V<sub>CE(SAT)</sub> < -150mV @ -1A.</li>
- R<sub>CE(sat)</sub> = 87mΩ for a low equivalent on-resistance
- 725mW power dissipation
- hFE characterised up to -6A for high current gain hold-up
- Complementary NPN Type: ZXTN649F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads
- Solderable per MIL-STD-202, Method 208
- Weight 0.008 grams (Approximate)

## Application

- MOSFET Gate Drivers
- Power Switching in Automotive and Industrial Applications
- Motor Drive and Control



### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP749FTA	1N8	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Notes:





# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-35	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ι <sub>C</sub>	-3	А
Peak Pulse Current	ICM	-6	А
Base Current	IB	-500	mA
Peak Pulse Current	I <sub>BM</sub>	-2	A

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	725	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	172	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R <sub>θJL</sub>	79	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

## ESD Ratings (Note 7)

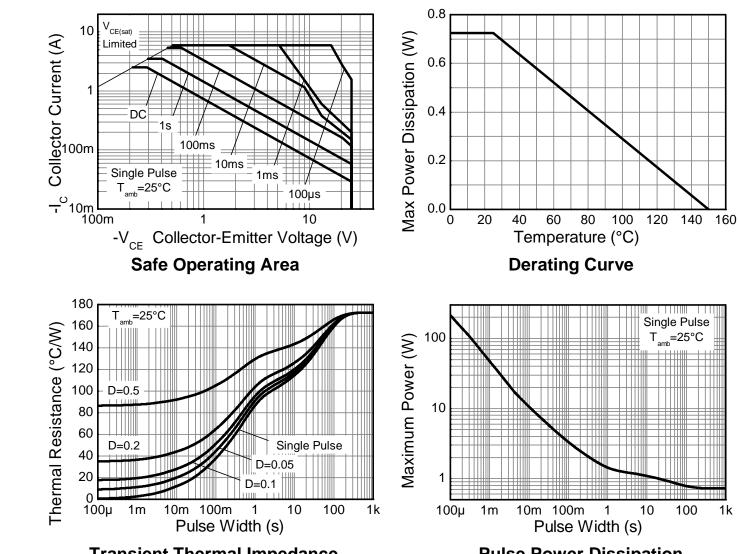
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1 oz. copper, in still air conditions; the device is Notes: easured when operating in a steady-state condition.
formal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



ZXTP749F

# Thermal Characteristics and Derating information



**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



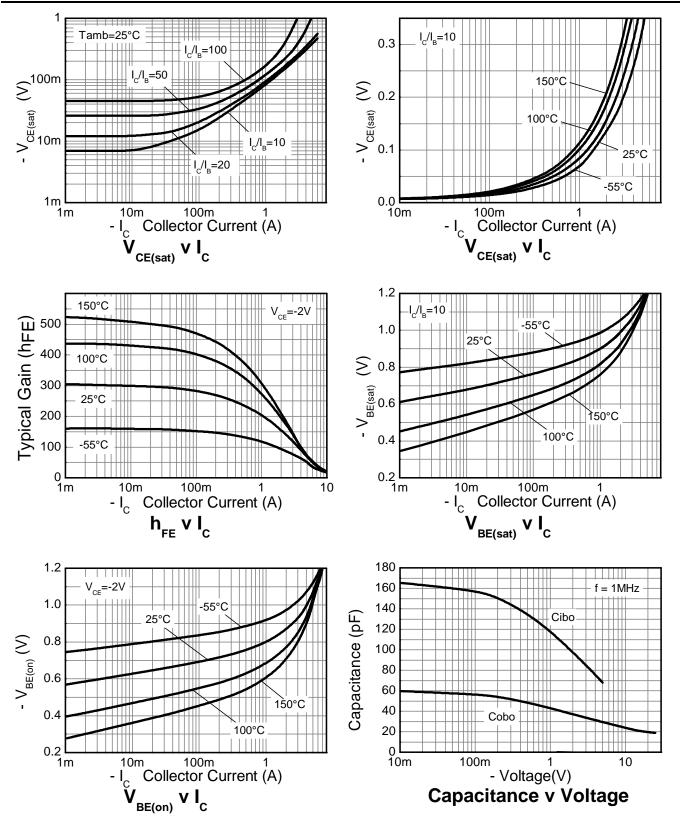
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-35	-60	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-25	-40	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.4	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	Ісво	-	<1	-50 -0.5	nA µA	V <sub>CB</sub> = -28V V <sub>CB</sub> = -28V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-50	nA	V <sub>EB</sub> = -5.6V
Static Forward Current Transfer Ratio (Note 8)	hfe	200 130 100 25	320 230 180 50	500 - - -	-	$\label{eq:lc} \begin{array}{l} I_{C} = -100 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_{C} = -1 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} = -2 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} = -6 \text{A}, \ V_{CE} = -2 \text{V} \end{array}$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	-	-85 -229	-150 -350	mV	$I_{C} = -1A, I_{B} = -100mA$ $I_{C} = -3A, I_{B} = -300mA$
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>	-	-786	-850	mV	$I_{C} = -1A, V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(sat)</sub>	-	-895	-1,000	mV	$I_{\rm C} = -1A, I_{\rm B} = -100 \text{mA}$

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



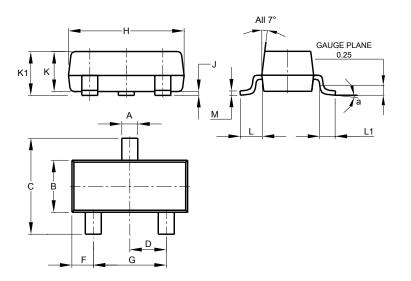
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

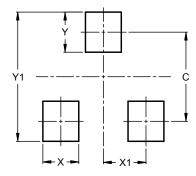
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
c	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		



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